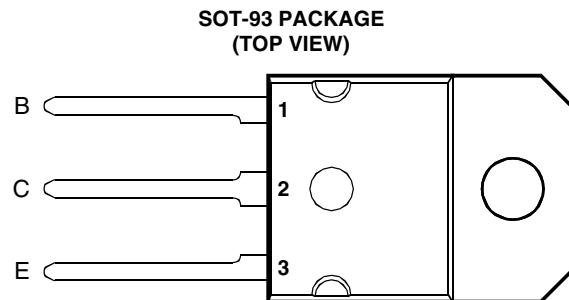


- Designed for Complementary Use with the BD250 Series
- 125 W at 25°C Case Temperature
- 25 A Continuous Collector Current
- 40 A Peak Collector Current
- Customer-Specified Selections Available



Pin 2 is in electrical contact with the mounting base.

MDTRAAA

### absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING		SYMBOL	VALUE	UNIT
Collector-emitter voltage ( $R_{BE} = 100 \Omega$ )	BD249	$V_{CER}$	55	V
	BD249A		70	
	BD249B		90	
	BD249C		115	
Collector-emitter voltage ( $I_C = 30 \text{ mA}$ )	BD249	$V_{CEO}$	45	V
	BD249A		60	
	BD249B		80	
	BD249C		100	
Emitter-base voltage	$V_{EBO}$		5	V
Continuous collector current	$I_C$		25	A
Peak collector current (see Note 1)	$I_{CM}$		40	A
Continuous base current	$I_B$		5	A
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)	$P_{tot}$		125	W
Continuous device dissipation at (or below) 25°C free air temperature (see Note 3)	$P_{tot}$		3	W
Unclamped inductive load energy (see Note 4)	$\frac{1}{2}L I_C^2$		90	mJ
Operating junction temperature range	$T_j$		-65 to +150	°C
Storage temperature range	$T_{stg}$		-65 to +150	°C
Lead temperature 3.2 mm from case for 10 seconds	$T_L$		250	°C

NOTES: 1. This value applies for  $t_p \leq 0.3 \text{ ms}$ , duty cycle  $\leq 10\%$ .

2. Derate linearly to 150°C case temperature at the rate of 1 W/°C.

3. Derate linearly to 150°C free air temperature at the rate of 24 mW/°C.

4. This rating is based on the capability of the transistor to operate safely in a circuit of:  $L = 20 \text{ mH}$ ,  $I_{B(on)} = 0.4 \text{ A}$ ,  $R_{BE} = 100 \Omega$ ,

$V_{BE(off)} = 0$ ,  $R_S = 0.1 \Omega$ ,  $V_{CC} = 20 \text{ V}$ .

### PRODUCT INFORMATION

**electrical characteristics at 25°C case temperature**

PARAMETER	TEST CONDITIONS			MIN	TYP	MAX	UNIT
$V_{(BR)CEO}$ Collector-emitter breakdown voltage	$I_C = 30 \text{ mA}$ (see Note 5)	$I_B = 0$	BD249 BD249A BD249B BD249C	45 60 80 100			V
$I_{CES}$ Collector-emitter cut-off current	$V_{CE} = 55 \text{ V}$ $V_{CE} = 70 \text{ V}$ $V_{CE} = 90 \text{ V}$ $V_{CE} = 115 \text{ V}$	$V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$	BD249 BD249A BD249B BD249C			0.7 0.7 0.7 0.7	mA
$I_{CEO}$ Collector cut-off current	$V_{CE} = 30 \text{ V}$ $V_{CE} = 60 \text{ V}$	$I_B = 0$ $I_B = 0$	BD249/249A BD249B/249C			1 1	mA
$I_{EBO}$ Emitter cut-off current	$V_{EB} = 5 \text{ V}$	$I_C = 0$				1	mA
$h_{FE}$ Forward current transfer ratio	$V_{CE} = 4 \text{ V}$ $V_{CE} = 4 \text{ V}$ $V_{CE} = 4 \text{ V}$	$I_C = 1.5 \text{ A}$ $I_C = 15 \text{ A}$ $I_C = 25 \text{ A}$	(see Notes 5 and 6)	25 10 5			
$V_{CE(sat)}$ Collector-emitter saturation voltage	$I_B = 1.5 \text{ A}$ $I_B = 5 \text{ A}$	$I_C = 15 \text{ A}$ $I_C = 25 \text{ A}$	(see Notes 5 and 6)			1.8 4	V
$V_{BE}$ Base-emitter voltage	$V_{CE} = 4 \text{ V}$ $V_{CE} = 4 \text{ V}$	$I_C = 15 \text{ A}$ $I_C = 25 \text{ A}$	(see Notes 5 and 6)			2 4	V
$h_{fe}$ Small signal forward current transfer ratio	$V_{CE} = 10 \text{ V}$	$I_C = 1 \text{ A}$	$f = 1 \text{ kHz}$	25			
$ h_{fel} $ Small signal forward current transfer ratio	$V_{CE} = 10 \text{ V}$	$I_C = 1 \text{ A}$	$f = 1 \text{ MHz}$	3			

NOTES: 5. These parameters must be measured using pulse techniques,  $t_p = 300 \mu\text{s}$ , duty cycle  $\leq 2\%$ .

6. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

**thermal characteristics**

PARAMETER	MIN	TYP	MAX	UNIT
$R_{\theta JC}$ Junction to case thermal resistance			1	°C/W
$R_{\theta JA}$ Junction to free air thermal resistance			42	°C/W

**resistive-load-switching characteristics at 25°C case temperature**

PARAMETER	TEST CONDITIONS <sup>†</sup>			MIN	TYP	MAX	UNIT
$t_{on}$ Turn-on time	$I_C = 5 \text{ A}$	$I_{B(on)} = 0.5 \text{ A}$	$I_{B(off)} = -0.5 \text{ A}$		0.3		μs
$t_{off}$ Turn-off time	$V_{BE(off)} = -5 \text{ V}$	$R_L = 5 \Omega$	$t_p = 20 \mu\text{s}, dc \leq 2\%$		0.9		μs

<sup>†</sup> Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

**PRODUCT INFORMATION**

## TYPICAL CHARACTERISTICS

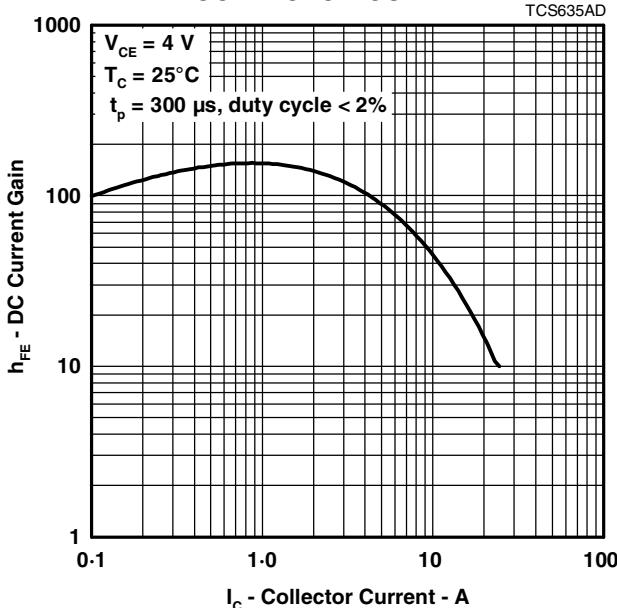
TYPICAL DC CURRENT GAIN  
VS  
COLLECTOR CURRENT

Figure 1.

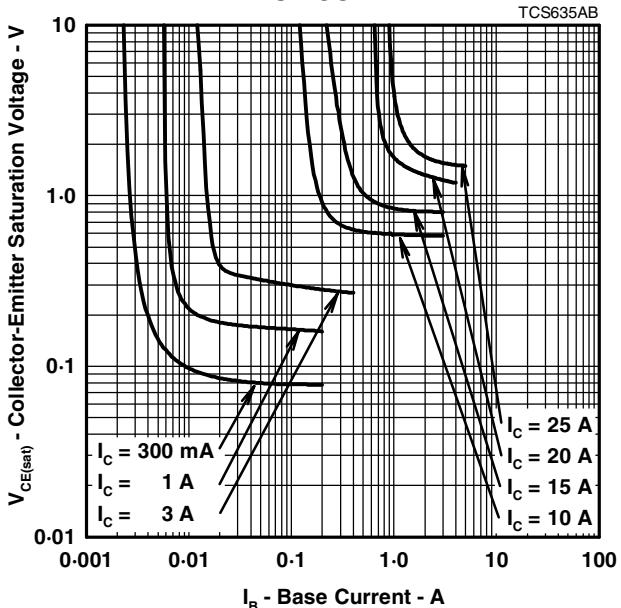
COLLECTOR-EMITTER SATURATION VOLTAGE  
VS  
BASE CURRENT

Figure 2.

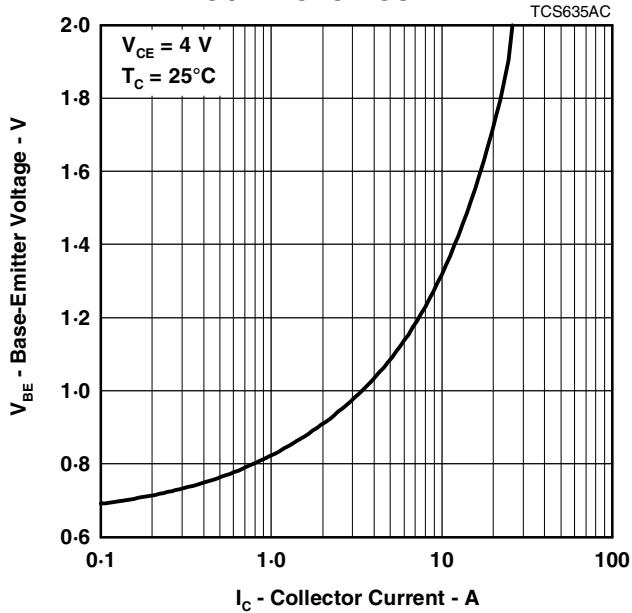
BASE-EMITTER VOLTAGE  
VS  
COLLECTOR CURRENT

Figure 3.

## PRODUCT INFORMATION

JUNE 1973 - REVISED SEPTEMBER 2002  
 Specifications are subject to change without notice.

### MAXIMUM SAFE OPERATING REGIONS

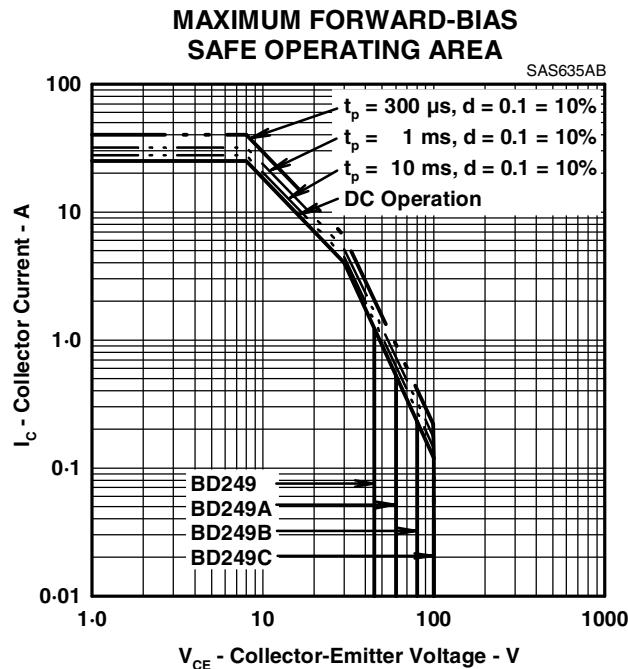


Figure 4.

### THERMAL INFORMATION

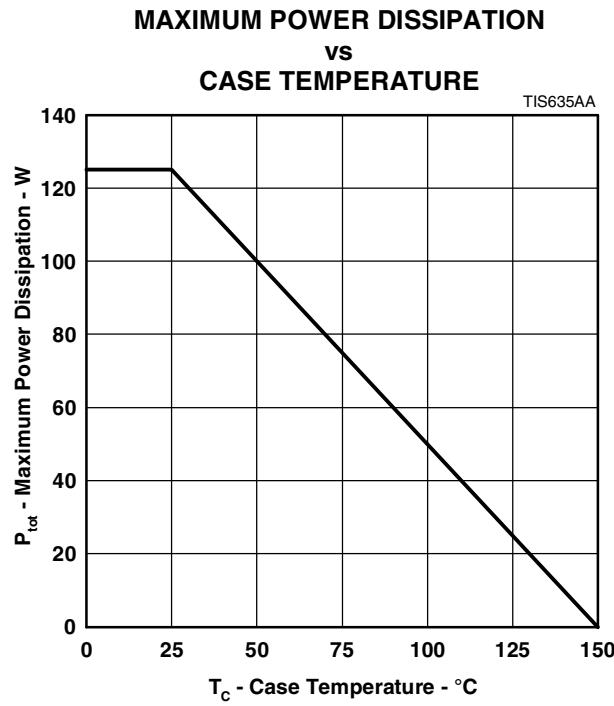


Figure 5.

### PRODUCT INFORMATION

# Mouser Electronics

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